

Switchmode Full Plastic Dual Ultrafast Power Rectifiers

...Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- * High Surge Capacity
- * Low Power Loss, High efficiency
- $*\,175^\circ\!\!\mathbb{C}$ Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage , High Current Capability
- * High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- * Flammability Classification 94V-O

* Pb free

* In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	URF2020C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
RMS Reverse Voltage	V _{R(RMS)}	140	V
Average Rectifier Forward Current Total Device (Rated V _R)	I _{F(AV)}	10 20	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz, TC=125°C)	I _{FM}	20	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	200	А
Operating Junction Temperature	T_{Jg}	175	°C
Storage Temperature Range	T _{stg}	-65 to +175	°C

ELECTRICAL CHARACTERISTICS

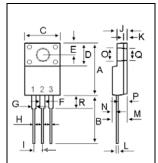
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 10 \text{ Amp } T_C = 125^{\circ}C$)	V _F		0.920 0.760	0.975 	V
$\label{eq:maximum lnstantaneous Reverse Current} (Rated DC Voltage, T_C = 25^{\circ}C) \\ (Rated DC Voltage, T_C = 125^{\circ}C) \\ \end{array}$	I _R		0.02 10.0	10.0 	uA
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	Trr			35	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	CP		140		₽F

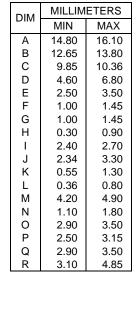


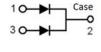
Ultrafast Power

RECTIFIERS









URF2020C



URF2020C

FIG-3 FORWARD CURRENT DERATING CURVE

20

16

12

8

0 L 0

350

-1.0A

25

50

75

LEAD TEMPERATURE (°C)

FIG-4TYPICAL JUNCTION CAPACITANCE

100

125

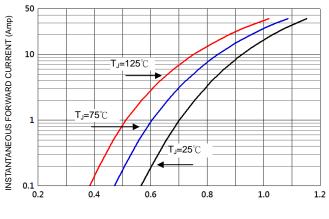
150

f = 1 M H z

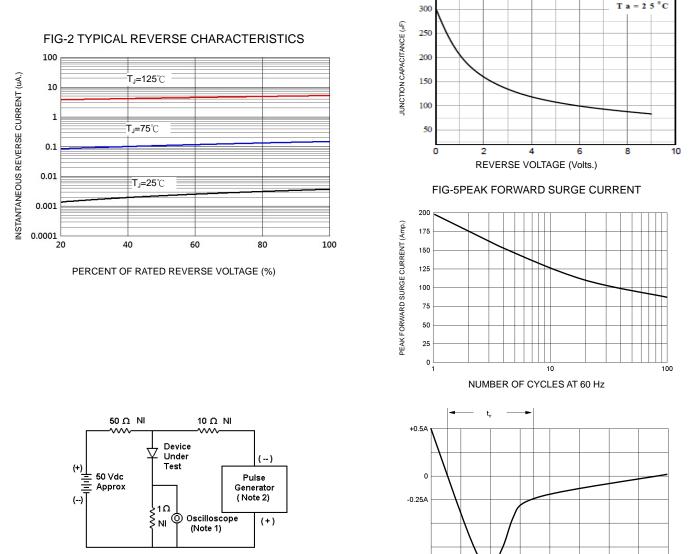
175

AVERAGE FORWARD RECTIFIED CURRENT (Amp.)

FIG-1 TYPICAL FORWARD CHARACTERISTICS



FORWARD VOLTAGE (Volts)



Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 10/20 ns/cm FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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